

# LMH6723/LMH6724/LMH6725 Single/Dual/Quad 370 MHz 1 mA Current Feedback Operational Amplifier

Check for Samples: [LMH6723](#), [LMH6724](#), [LMH6725](#)

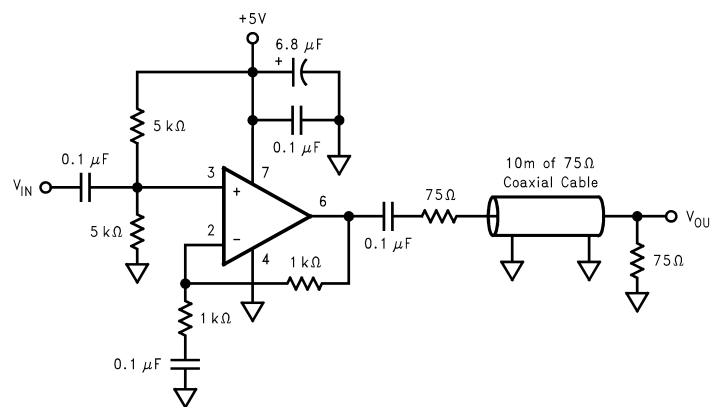
## FEATURES

- Large Signal Bandwidth and Slew Rate 100% Tested
- 370 MHz Bandwidth ( $A_V = 1$ ,  $V_{OUT} = 0.5 V_{PP}$ ) -3 dB BW
- 260 MHz ( $A_V = +2 V/V$ ,  $V_{OUT} = 0.5 V_{PP}$ ) -3 dB BW
- 1 mA Supply Current
- 110 mA Linear Output Current
- 0.03%, 0.11° Differential Gain, Phase
- 0.1 dB Gain Flatness to 100 MHz
- Fast Slew Rate: 600 V/ $\mu$ s
- Unity Gain Stable
- Single Supply Range of 4.5 to 12V
- Improved Replacement for CLC450, CLC452, (LMH6723)

## APPLICATIONS

- Line Driver
- Portable Video
- A/D Driver
- Portable DVD

## Typical Application


**Figure 1. Single Supply Cable Driver**

## DESCRIPTION

The LMH6723/LMH6724/LMH6725 provides a 260 MHz small signal bandwidth at a gain of +2 V/V and a 600 V/ $\mu$ s slew rate while consuming only 1 mA from  $\pm 5V$  supplies.

The LMH6723/LMH6724/LMH6725 supports video applications with its 0.03% and 0.11° differential gain and phase for NTSC and PAL video signals. The LMH6723/LMH6724/LMH6725 also offers a flat gain response of 0.1 dB to 100 MHz. Additionally, the LMH6723/LMH6724/LMH6725 can deliver 110 mA of linear output current. This level of performance, as well as a wide supply range of 4.5 to 12V, makes the LMH6723/LMH6724/LMH6725 an ideal op amp for a variety of portable applications. The LMH6723/LMH6724/LMH6725's small packages (TSSOP, SOIC and SOT-23), low power requirement and high performance allow the LMH6723/LMH6724/LMH6725 to serve a wide variety of portable applications.

The LMH6723/LMH6724/LMH6725 is manufactured in Texas Instruments' VIP10 complimentary bipolar process.



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### Absolute Maximum Ratings<sup>(1)(2)</sup>

$V_{CC}$ ( $V^+ - V^-$ )		$\pm 6.75V$
$I_{OUT}$		120 mA <sup>(3)</sup>
Common Mode Input Voltage		$\pm V_{CC}$
Maximum Junction Temperature		+150°C
Storage Temperature Range		-65°C to +150°C
Soldering Information	Infrared or Convection (20 sec)	235°C
	Wave Soldering (10 sec)	260°C
ESD Tolerance <sup>(4)</sup>		
Human Body Model		2000V
Machine Model		200V

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications, see the Electrical Characteristics tables.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.
- (3) The maximum continuous output current ( $I_{OUT}$ ) is determined by device power dissipation limitations. See the [POWER DISSIPATION](#) section for more details.
- (4) Human Body Model, 1.5 k $\Omega$  in series with 100 pF. Machine Model, 0 $\Omega$  in series with 200 pF.

### Operating Ratings<sup>(1)</sup>

Thermal Resistance	
Package	( $\theta_{JA}$ )
8-Pin SOIC	166°C/W
5-Pin SOT-23	230°C/W
14-Pin SOIC	130°C/W
14-Pin TSSOP	160°C/W
Operating Temperature Range	-40°C to +85°C
Nominal Supply Voltage	4.5V to 12V

- (1) The maximum continuous output current ( $I_{OUT}$ ) is determined by device power dissipation limitations. See the [POWER DISSIPATION](#) section for more details.

## ±5V Electrical Characteristics

Unless otherwise specified,  $A_V = +2$ ,  $R_F = 1200\Omega$ ,  $R_L = 100\Omega$ . **Boldface** limits apply at temperature extremes.<sup>(1)</sup>

Parameter	Test Conditions	Min	Typ	Max	Units		
<b>Frequency Domain Response</b>							
SSBW	-3 dB Bandwidth Small Signal	$V_{OUT} = 0.5 V_{PP}$		260	MHz		
LSBW	-3dB Bandwidth Large Signal	$V_{OUT} = 4.0 V_{PP}$		LMH6723	90	110	MHz
				LMH6724	85	95	
				LMH6725			
UGBW	-3 dB Bandwidth Unity Gain	$V_{OUT} = .2 V_{PP}$ $A_V = 1 V/V$		370	MHz		
.1dB BW	.1 dB Bandwidth	$V_{OUT} = 0.5 V_{PP}$		100	MHz		
DG	Differential Gain	$R_L = 150\Omega$ , 4.43 MHz		0.03	%		
DP	Differential Phase	$R_L = 150\Omega$ , 4.43 MHz		0.11	deg		
<b>Time Domain Response</b>							
TRS	Rise and Fall Time	4V Step		2.5	ns		
TSS	Settling Time to 0.05%	2V Step		30	ns		
SR	Slew Rate	4V Step		500	600	V/ $\mu$ s	
<b>Distortion and Noise Response</b>							
HD2	2 <sup>nd</sup> Harmonic Distortion	2 $V_{PP}$ , 5 MHz		-65	dBc		
HD3	3 <sup>rd</sup> Harmonic Distortion	2 $V_{PP}$ , 5 MHz		-63	dBc		
<b>Equivalent Input Noise</b>							
VN	Non-Inverting Voltage Noise	>1 MHz		4.3	nV/ $\sqrt{Hz}$		
NICN	Inverting Current Noise	>1 MHz		6	pA/ $\sqrt{Hz}$		
ICN	Non-Inverting Current Noise	>1 MHz		6	pA/ $\sqrt{Hz}$		
<b>Static, DC Performance</b>							
$V_{IO}$	Input Offset Voltage			1	$\pm 3$ <b><math>\pm 3.7</math></b>	mV	
$I_{BN}$	Input Bias Current	Non-Inverting		-2	$\pm 4$ <b><math>\pm 5</math></b>	$\mu$ A	
$I_{BI}$	Input Bias Current	Inverting		0.4	$\pm 4$ <b><math>\pm 5</math></b>	$\mu$ A	
PSRR	Power Supply Rejection Ratio	DC, 1V Step	LMH6723	59 <b>57</b>	64	dB	
			LMH6724	59 <b>55</b>	64		
			LMH6725	59 <b>56</b>	64		
CMRR	Common Mode Rejection Ratio	DC, 1V Step	LMH6723	57 <b>55</b>	60	dB	
			LMH6724	57 <b>53</b>	60		
			LMH6725	57 <b>54</b>	60		
$I_{CC}$	Supply Current (per amplifier)	$R_L = \infty$		1	1.2 <b>1.4</b>	mA	

(1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that  $T_J = T_A$ . No ensured specification of parametric performance is indicated in the electrical tables under conditions of internal self heating where  $T_J > T_A$ . See [Application Section](#) for information on temperature derating of this device. Min/Max ratings are based on product characterization and simulation. Individual parameters are tested as noted.

### ±5V Electrical Characteristics (continued)

Unless otherwise specified,  $A_V = +2$ ,  $R_F = 1200\Omega$ ,  $R_L = 100\Omega$ . **Boldface** limits apply at temperature extremes.<sup>(1)</sup>

Parameter		Test Conditions	Min	Typ	Max	Units
<b>Miscellaneous Performance</b>						
$R_{IN+}$	Input Resistance	Non-Inverting		100		k $\Omega$
$R_{IN-}$	Input Resistance (Output Resistance of Input Buffer)	Inverting		500		$\Omega$
$C_{IN}$	Input Capacitance	Non-Inverting		1.5		pF
$R_{OUT}$	Output Resistance	Closed Loop		0.01		$\Omega$
$V_O$	Output Voltage Range	$R_L = \infty$	LMH6723	$\pm 4$ <b><math>\pm 3.9</math></b>	$\pm 4.1$	V
			LMH6724 LMH6725	$\pm 4$ <b><math>\pm 3.85</math></b>	$\pm 4.1$	
$V_{OL}$	Output Voltage Range, High	$R_L = 100\Omega$	3.6 <b>3.5</b>	3.7		V
	Output Voltage Range, Low	$R_L = 100\Omega$	-3.25 <b>-3.1</b>	-3.45		
CMVR	Input Voltage Range	Common Mode, CMRR > 50 dB	$\pm 4.0$			V
$I_O$	Output Current	Sourcing, $V_{OUT} = 0$	95 <b>70</b>	110		mA
		Sinking, $V_{OUT} = 0$	-80 <b>-70</b>	110		

### ±2.5V Electrical Characteristics

Unless otherwise specified,  $A_V = +2$ ,  $R_F = 1200\Omega$ ,  $R_L = 100\Omega$ . **Boldface** limits apply at temperature extremes.<sup>(1)</sup>

Parameter		Test Conditions	Min	Typ	Max	Units
<b>Frequency Domain Response</b>						
SSBW	-3 dB Bandwidth Small Signal	$V_{OUT} = 0.5 V_{PP}$		210		MHz
LSBW	-3 dB Bandwidth Large Signal	$V_{OUT} = 2.0 V_{PP}$	LMH6723 LMH6724	95	125	MHz
			LMH6725	90	100	
UGBW	-3 dB Bandwidth Unity Gain	$V_{OUT} = 0.5 V_{PP}$ , $A_V = 1 V/V$		290		MHz
.1dB BW	.1 dB Bandwidth	$V_{OUT} = 0.5 V_{PP}$		100		MHz
DG	Differential Gain	$R_L = 150\Omega$ , 4.43 MHz		.03		%
DP	Differential Phase	$R_L = 150\Omega$ , 4.43 MHz		0.1		deg
<b>Time Domain Response</b>						
TRS	Rise and Fall Time	2V Step		4		ns
SR	Slew Rate	2V Step	275	400		V/ $\mu$ s
<b>Distortion and Noise Response</b>						
HD2	2 <sup>nd</sup> Harmonic Distortion	2 $V_{PP}$ , 5 MHz		-67		dBc
HD3	3 <sup>rd</sup> Harmonic Distortion	2 $V_{PP}$ , 5 MHz		-67		dBc
<b>Equivalent Input Noise</b>						
VN	Non-Inverting Voltage	>1 MHz		4.3		nV/ $\sqrt{Hz}$
NICN	Inverting Current	>1MHz		6		pA/ $\sqrt{Hz}$
ICN	Non-Inverting Current	>1MHz		6		pA/ $\sqrt{Hz}$

(1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that  $T_J = T_A$ . No ensured specification of parametric performance is indicated in the electrical tables under conditions of internal self heating where  $T_J > T_A$ . See [Application Section](#) for information on temperature derating of this device. Min/Max ratings are based on product characterization and simulation. Individual parameters are tested as noted.

**±2.5V Electrical Characteristics (continued)**

 Unless otherwise specified,  $A_V = +2$ ,  $R_F = 1200\Omega$ ,  $R_L = 100\Omega$ . **Boldface** limits apply at temperature extremes.<sup>(1)</sup>

Parameter		Test Conditions		Min	Typ	Max	Units
<b>Static, DC Performance</b>							
$V_{IO}$	Input Offset Voltage				-0.5	$\pm 3$ <b><math>\pm 3.4</math></b>	mV
$I_{BN}$	Input Bias Current	Non-Inverting			-2.7	$\pm 4$ <b><math>\pm 5</math></b>	$\mu A$
$I_{BI}$	Input Bias Current	Inverting			-0.7	$\pm 4$ <b><math>\pm 5</math></b>	$\mu A$
PSRR	Power Supply Rejection Ratio	DC, 0.5V Step	LMH6723	59 <b>57</b>	62		dB
			LMH6724	58 <b>55</b>	62		
			LMH6725	59 <b>56</b>	62		
CMRR	Common Mode Rejection Ratio	DC, 0.5V Step	LMH6723	57 <b>53</b>	59		dB
			LMH6724	55 <b>52</b>	59		
			LMH6725	57 <b>52</b>	59		
$I_{CC}$	Supply Current (per amplifier)	$R_L = \infty$			0.9	1.1 <b>1.3</b>	mA
<b>Miscellaneous Performance</b>							
$R_{IN+}$	Input Resistance	Non-Inverting			100		k $\Omega$
$R_{IN-}$	Input Resistance (Output Resistance of Input Buffer)	Inverting			500		$\Omega$
$C_{IN}$	Input Capacitance	Non-Inverting			1.5		pF
$R_{OUT}$	Output Resistance	Closed Loop			0.02		$\Omega$
$V_O$	Output Voltage Range	$R_L = \infty$		$\pm 1.55$ <b><math>\pm 1.4</math></b>	$\pm 1.65$		V
$V_{OL}$	Output Voltage Range, High	$R_L = 100\Omega$	LMH6723	1.35 <b>1.27</b>	1.45		V
			LMH6724 LMH6725	1.35 <b>1.26</b>	1.45		
	Output Voltage Range, Low	$R_L = 100\Omega$	LMH6723	-1.25 <b>-1.15</b>	-1.38		V
			LMH6724 LMH6725	-1.25 <b>-1.15</b>	-1.38		
CMVR	Input Voltage Range	Common Mode, CMRR > 50 dB		$\pm 1.45$			V
$I_O$	Output Current	Sourcing		70 <b>60</b>	90		mA
		Sinking		-30 <b>-30</b>	-60		

Connection Diagrams

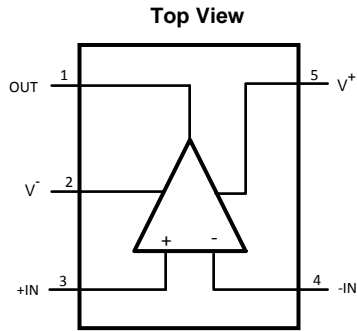


Figure 2. 5-Pin SOT-23 Package (LMH6723)  
See Package Number DBV0005A

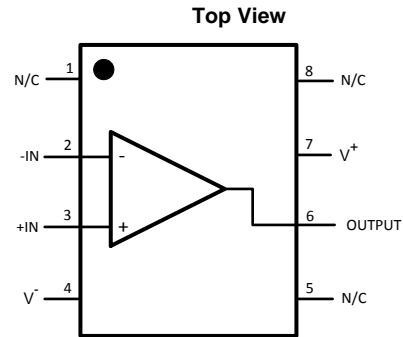


Figure 3. 8-Pin SOIC Package (LMH6723)  
See Package Number D0008A

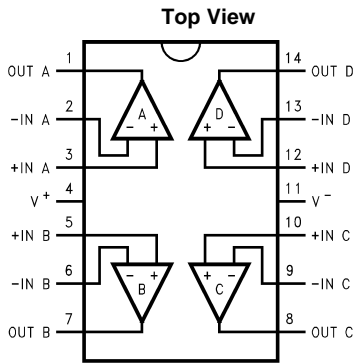


Figure 4. 14-Pin SOIC Package (LMH6725)  
See Package Number D0014A

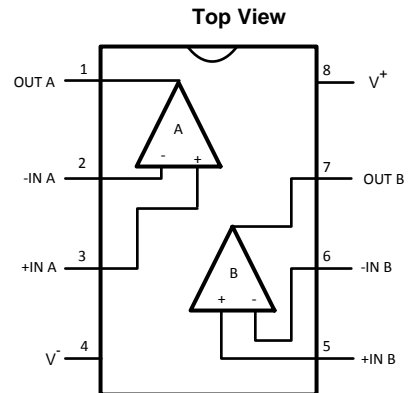


Figure 5. 8-Pin TSSOP Package (LMH6724)  
See Package Number PW0014A

Typical Performance Characteristics

$A_V = 2$ ,  $R_F = 1200\Omega$ ,  $R_L = 100\Omega$ , unless otherwise specified.

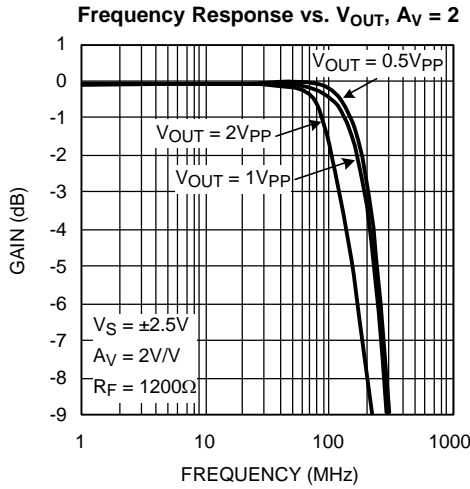


Figure 6.

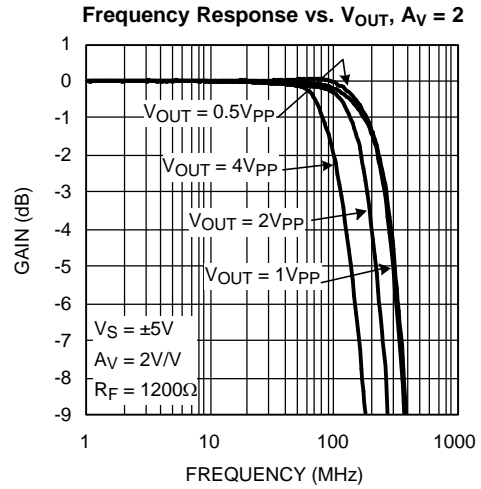


Figure 7.

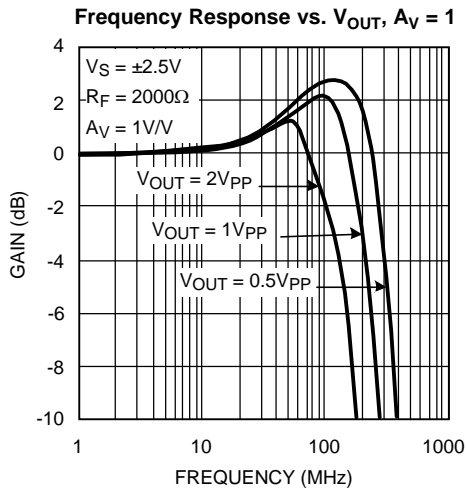


Figure 8.

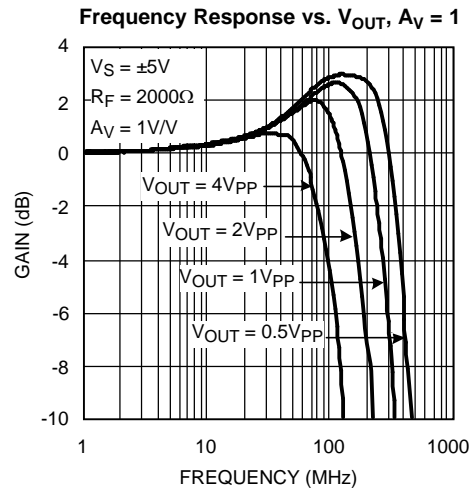


Figure 9.

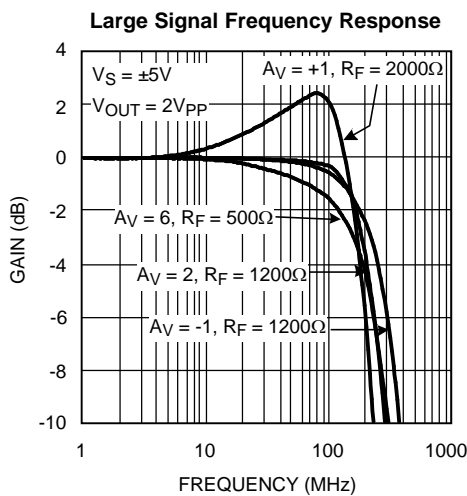


Figure 10.

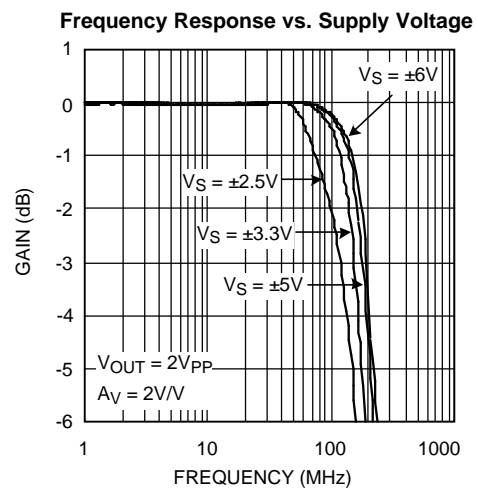
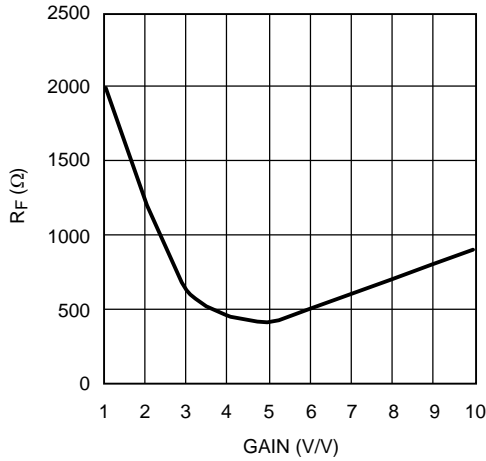


Figure 11.

**Typical Performance Characteristics (continued)**

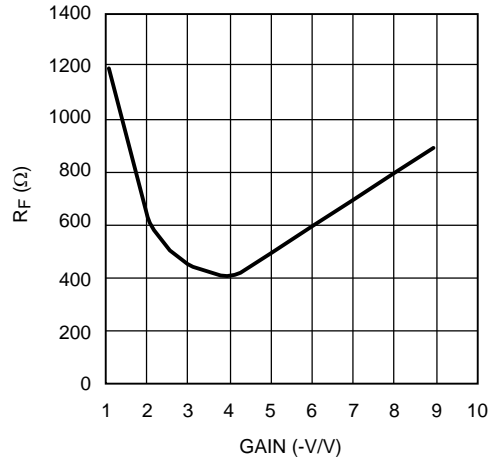
$A_V = 2$ ,  $R_F = 1200\Omega$ ,  $R_L = 100\Omega$ , unless otherwise specified.

**Suggested  $R_F$  vs. Gain Non-Inverting**



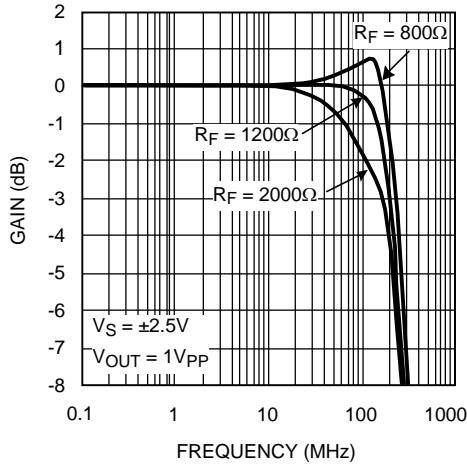
**Figure 12.**

**Suggested  $R_F$  vs. Gain Inverting**



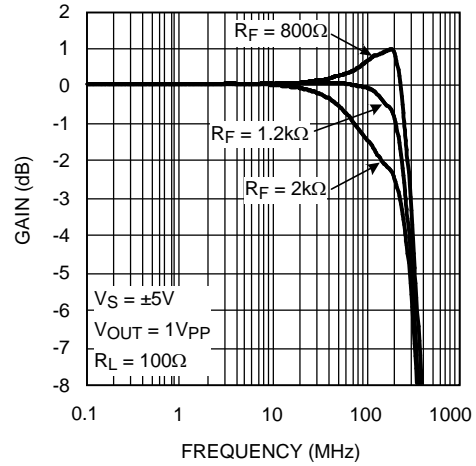
**Figure 13.**

**Frequency Response vs.  $R_F$**



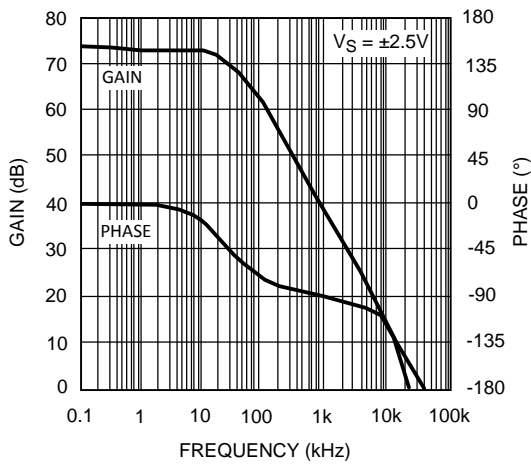
**Figure 14.**

**Frequency Response vs.  $R_F$**



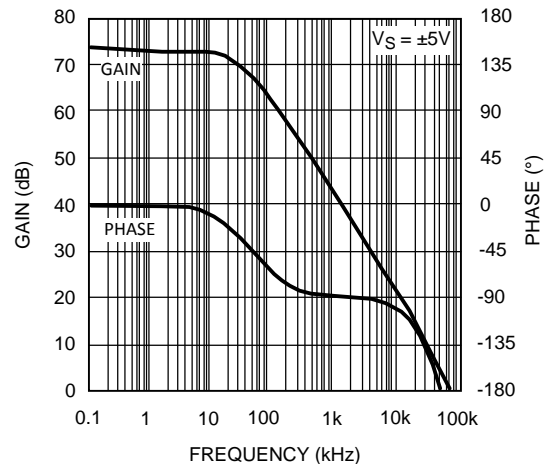
**Figure 15.**

**Open Loop Gain & Phase**



**Figure 16.**

**Open Loop Gain & Phase**



**Figure 17.**

Typical Performance Characteristics (continued)

$A_V = 2$ ,  $R_F = 1200\Omega$ ,  $R_L = 100\Omega$ , unless otherwise specified.

HD2 & HD3 vs.  $V_{OUT}$

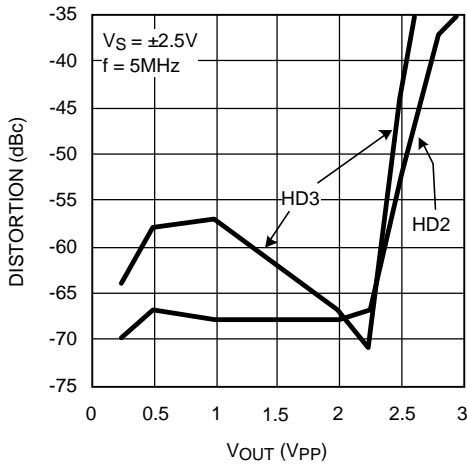


Figure 18.

HD2 & HD3 vs.  $V_{OUT}$

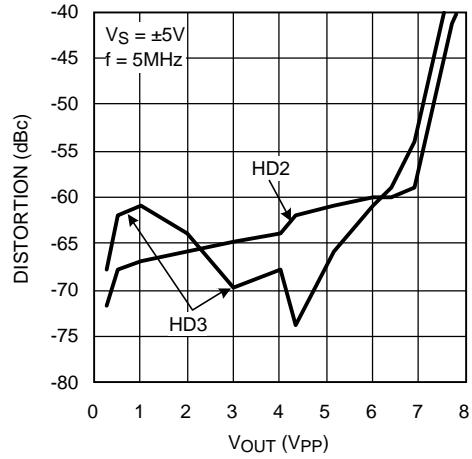


Figure 19.

HD2 & HD3 vs. Frequency

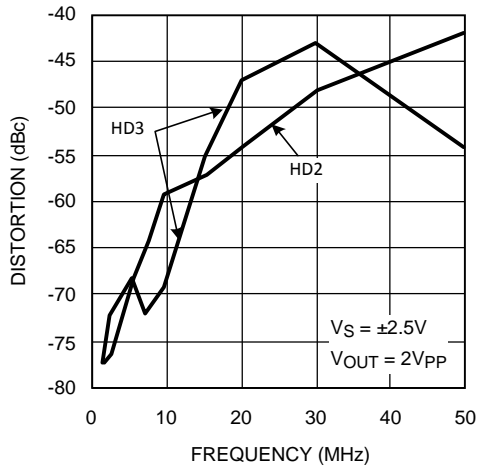


Figure 20.

HD2 & HD3 vs. Frequency

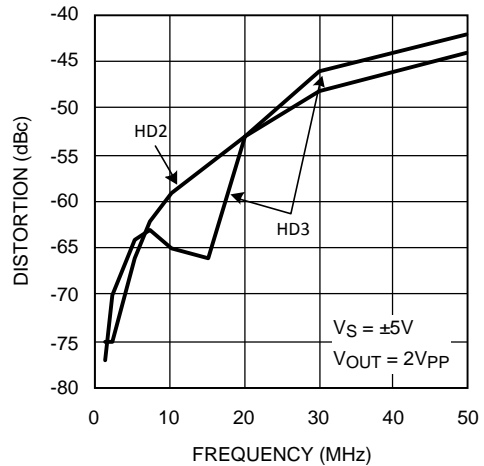


Figure 21.

Frequency Response vs.  $C_L$

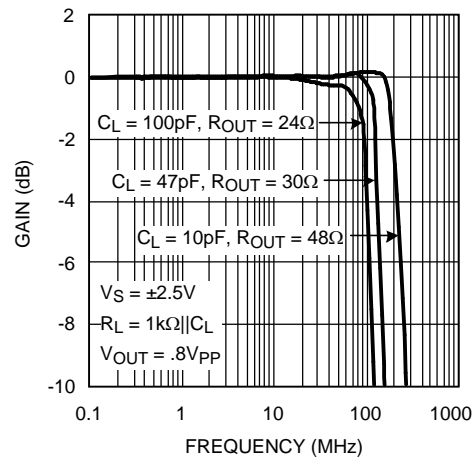


Figure 22.

Frequency Response vs.  $C_L$

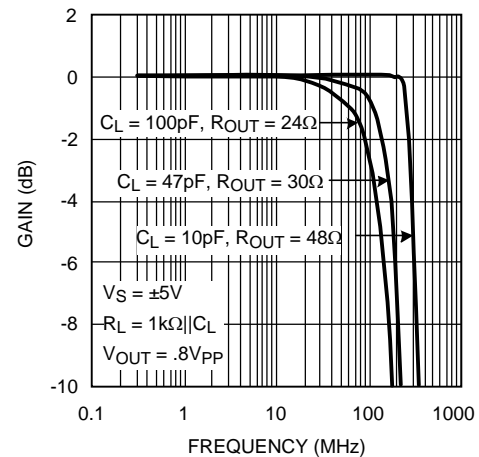


Figure 23.

**Typical Performance Characteristics (continued)**

$A_V = 2$ ,  $R_F = 1200\Omega$ ,  $R_L = 100\Omega$ , unless otherwise specified.

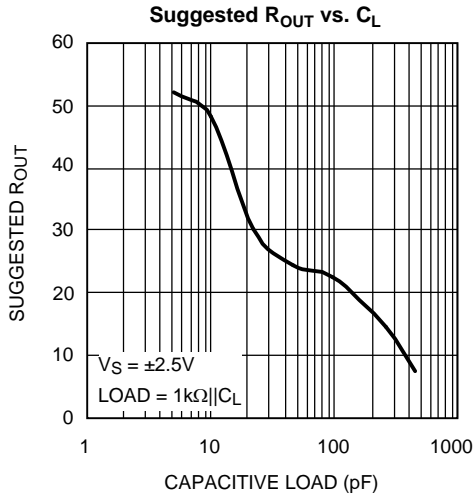


Figure 24.

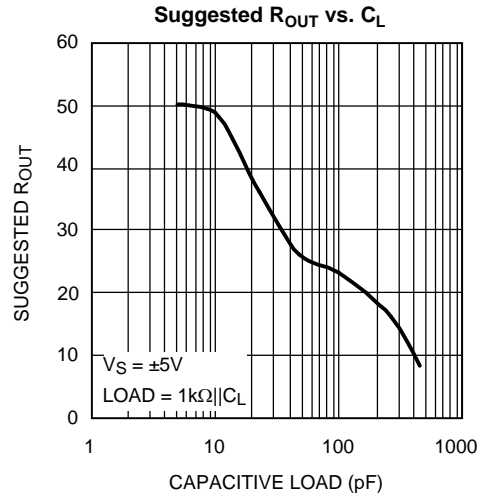


Figure 25.

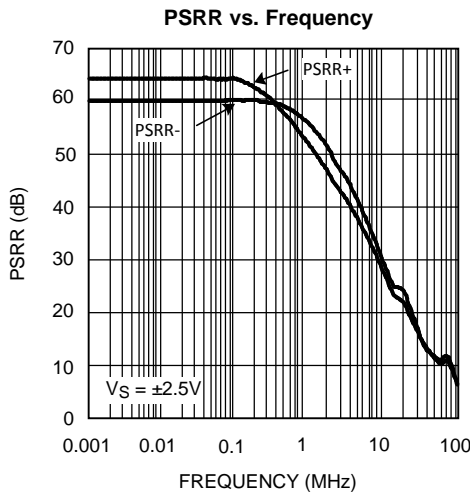


Figure 26.

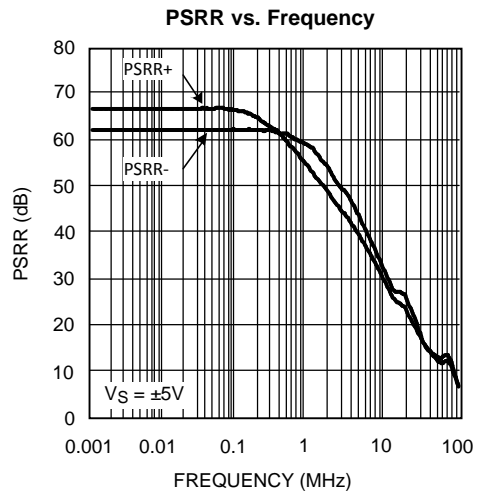


Figure 27.

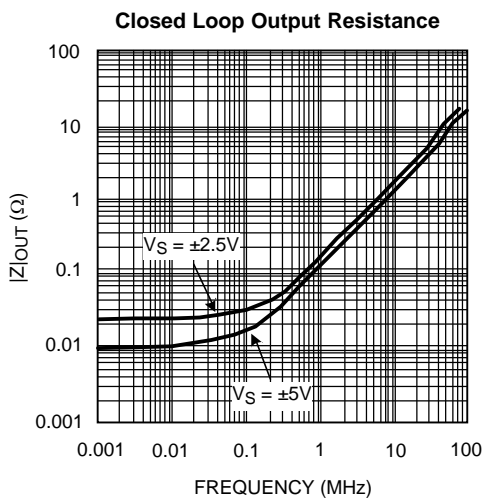


Figure 28.

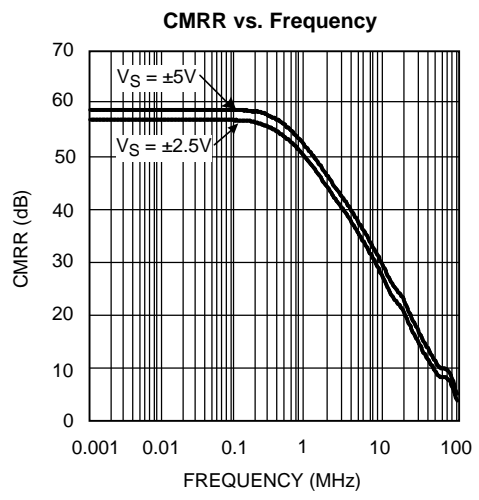


Figure 29.

Typical Performance Characteristics (continued)

$A_V = 2$ ,  $R_F = 1200\Omega$ ,  $R_L = 100\Omega$ , unless otherwise specified.

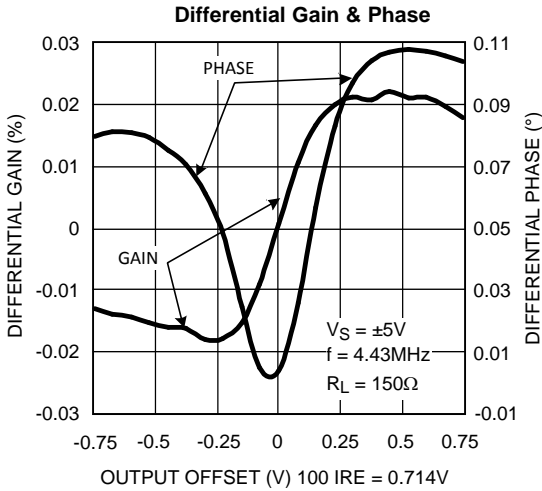


Figure 30.

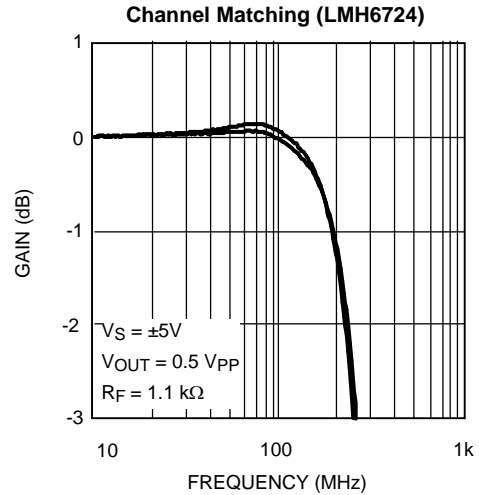


Figure 31.

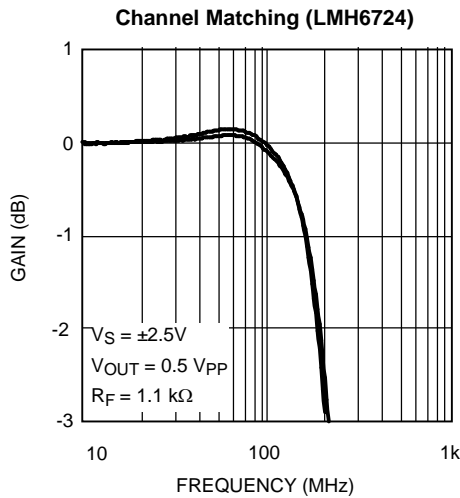


Figure 32.

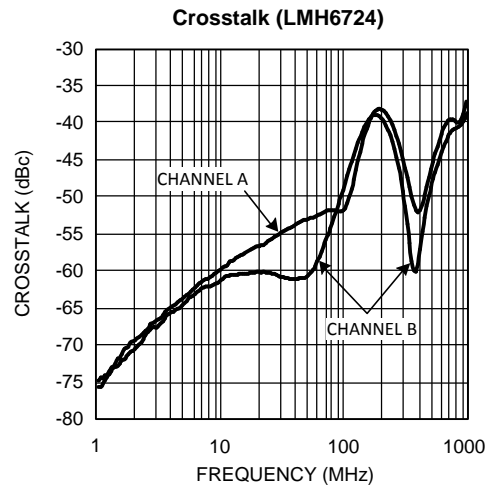


Figure 33.

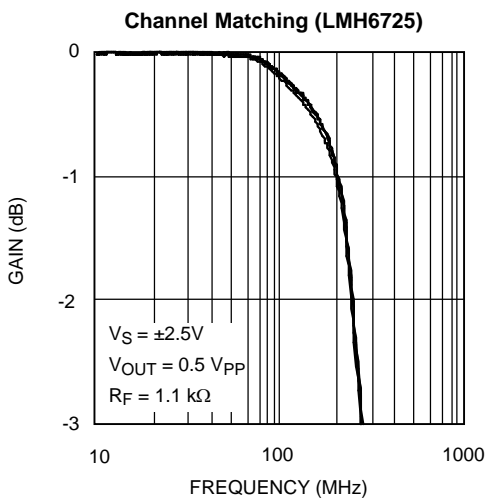


Figure 34.

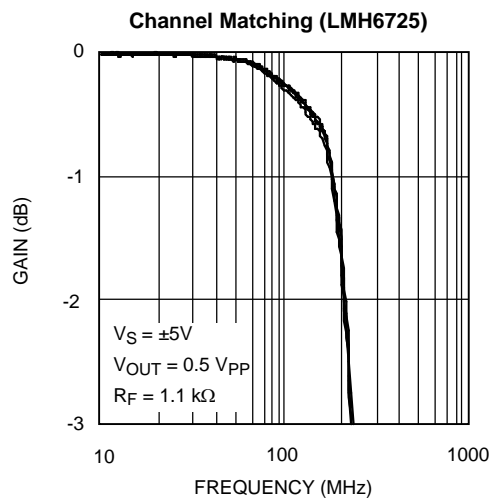
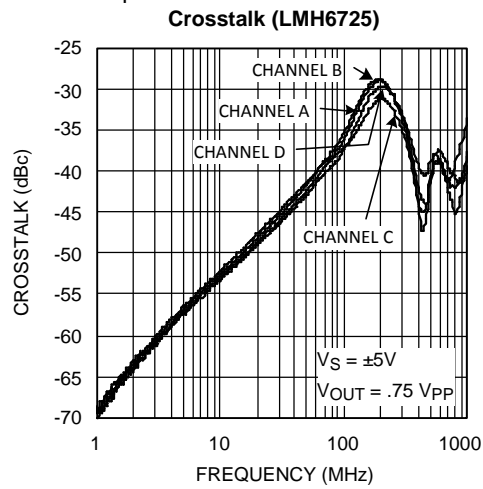


Figure 35.

**Typical Performance Characteristics (continued)**

$A_V = 2$ ,  $R_F = 1200\Omega$ ,  $R_L = 100\Omega$ , unless otherwise specified.



## APPLICATION SECTION

### GENERAL INFORMATION

The LMH6723/LMH6724/LMH6725 is a high speed current feedback amplifier manufactured on Texas Instruments' VIP10 (Vertically Integrated PNP) complimentary bipolar process. LMH6723/LMH6724/LMH6725 offers a unique combination of high speed and low quiescent supply current making it suitable for a wide range of battery powered and portable applications that require high performance. This amplifier can operate from 4.5V to 12V nominal supply voltages and draws only 1 mA of quiescent supply current at 10V supplies ( $\pm 5V$  typically). The LMH6723/LMH6724/LMH6725 has no internal ground reference so single or split supply configurations are both equally useful.

### EVALUATION BOARDS

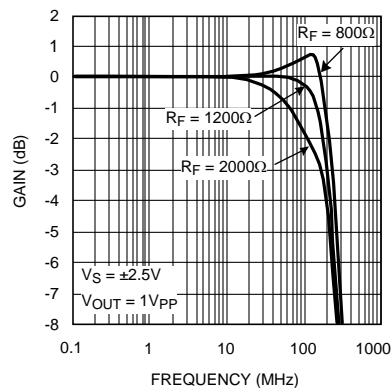
Texas Instruments provides the following evaluation boards as a guide for high frequency layout and as an aid in device testing and characterization. Many of the datasheet plots were measured with these boards.

Device	Package	Board Part Number
LMH6723MA	SOIC-8	LMH730227
LMH6723MF	SOT-23	LMH730216
LMH6724MA	SOIC-8	LMH730036
LMH6725MA	SOIC-14	LMH730231

These evaluation boards can be shipped when a device sample request is placed with Texas Instruments.

### FEEDBACK RESISTOR SELECTION

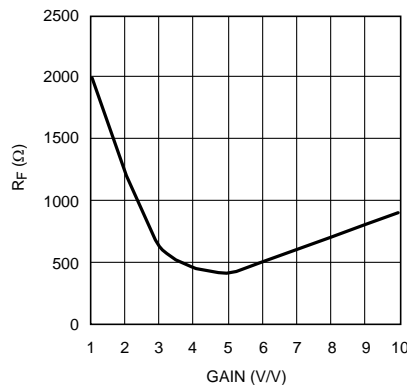
One of the key benefits of a current feedback operational amplifier is the ability to maintain optimum frequency response independent of gain by using appropriate values for the feedback resistor ( $R_F$ ). The Electrical Characteristics and Typical Performance plots were generated with an  $R_F$  of  $1200\Omega$ , a gain of  $+2V/V$  and  $\pm 5V$  or  $\pm 2.5V$  power supplies (unless otherwise specified). Generally, lowering  $R_F$  from its recommended value will peak the frequency response and extend the bandwidth; however, increasing the value of  $R_F$  will cause the frequency response to roll off faster. Reducing the value of  $R_F$  too far below its recommended value will cause overshoot, ringing and, eventually, oscillation.



**Figure 37. Frequency Response vs.  $R_F$**

Figure 37 shows the LMH6723/LMH6724/LMH6725's frequency response as  $R_F$  is varied ( $R_L = 100\Omega$ ,  $A_V = +2$ ). This plot shows that an  $R_F$  of  $800\Omega$  results in peaking. An  $R_F$  of  $1200\Omega$  gives near maximal bandwidth and gain flatness with good stability. Since each application is slightly different it is worth some experimentation to find the optimal  $R_F$  for a given circuit. In general a value of  $R_F$  that produces  $-0.1$  dB of peaking is the best compromise between stability and maximal bandwidth. Note that it is not possible to use a current feedback amplifier with the output shorted directly to the inverting input. The buffer configuration of the LMH6723/LMH6724/LMH6725 requires a  $2000\Omega$  feedback resistor for stable operation. For other gains see the charts Figure 38 and Figure 39. These charts provide a good place to start when selecting the best feedback resistor value for a variety of gain settings.

For more information see Application Note OA-13 which describes the relationship between  $R_F$  and closed-loop frequency response for current feedback operational amplifiers. The value for the inverting input impedance for the LMH6723/LMH6724/LMH6725 is approximately  $500\Omega$ . The LMH6723/LMH6724/LMH6725 is designed for optimum performance at gains of  $+1$  to  $+5V/V$  and  $-1$  to  $-4V/V$ . Higher gain configurations are still useful; however, the bandwidth will fall as gain is increased, much like a typical voltage feedback amplifier.



**Figure 38. RF vs. Non-Inverting Gain**

Figure 38 and Figure 39 show the value of  $R_F$  versus gain. A higher  $R_F$  is required at higher gains to keep  $R_G$  from decreasing too far below the input impedance of the inverting input. This limitation applies to both inverting and non-inverting configurations. For the LMH6723/LMH6724/LMH6725 the input resistance of the inverting input is approximately  $500\Omega$  and  $100\Omega$  is a practical lower limit for  $R_G$ . The LMH6723/LMH6724/LMH6725 begins to operate in a gain bandwidth limited fashion in the region where  $R_F$  must be increased for higher gains. Note that the amplifier will operate with  $R_G$  values well below  $100\Omega$ ; however, results will be substantially different than predicted from ideal models. In particular, the voltage potential between the Inverting and Non-Inverting inputs cannot be expected to remain small.

For inverting configurations the impedance seen by the source is  $R_G \parallel R_T$ . For most sources this limits the maximum inverting gain since  $R_F$  is determined by the desired gain as shown in Figure 39. The value of  $R_G$  is then  $R_F/\text{Gain}$ . Thus for an inverting gain of  $-4$  V/V the input impedance is equal to  $100\Omega$ . Using a termination resistor, this can be brought down to match a  $50\Omega$  or  $75\Omega$  source; however, a  $150\Omega$  source cannot be matched without a severe compromise in  $R_F$ .

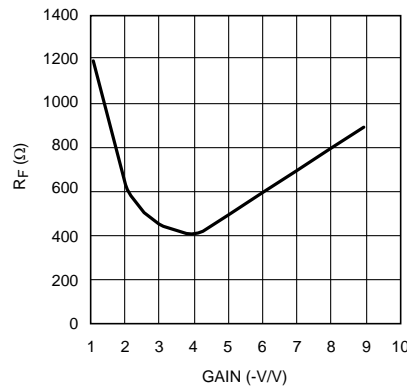


Figure 39.  $R_F$  vs. Inverting Gain

### ACTIVE FILTERS

When using any current feedback operational amplifier as an active filter it is necessary to be careful using reactive components in the feedback loop. Reducing the feedback impedance, especially at higher frequencies, will almost certainly cause stability problems. Likewise capacitance on the inverting input should be avoided. See Application Notes OA-07 and OA-26 for more information on Active Filter applications for Current Feedback Op Amps.

When using the LMH6723/LMH6724/LMH6725 as a low-pass filter the value of  $R_F$  can be substantially reduced from the value recommended in the  $R_F$  vs. Gain charts. The benefit of reducing  $R_F$  is increased gain at higher frequencies, which improves attenuation in the stop band. Stability problems are avoided because in the stop band additional device bandwidth is used to cancel the input signal rather than amplify it. The benefit of this change depends on the particulars of the circuit design. With a high pass filter configuration reducing  $R_F$  will likely result in device instability and is not recommended.

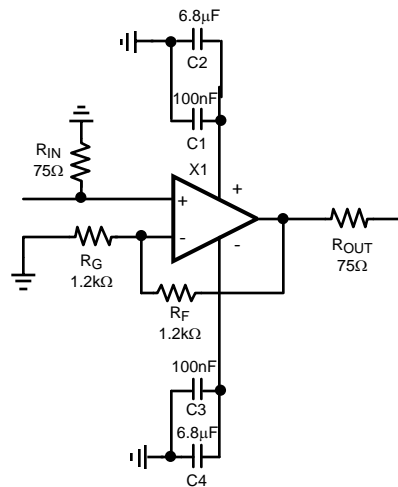


Figure 40. Typical Application with Suggested Supply Bypassing

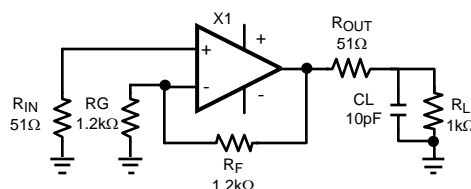


Figure 41. Decoupling Capacitive Loads

## DRIVING CAPACITIVE LOADS

Capacitive output loading applications will benefit from the use of a series output resistor as shown in Figure 41. The charts "Suggested  $R_{OUT}$  vs. Cap Load" give a recommended value for selecting a series output resistor for mitigating capacitive loads. The values suggested in the charts are selected for .5 dB or less of peaking in the frequency response. This gives a good compromise between settling time and bandwidth. For applications where maximum frequency response is needed and some peaking is tolerable, the value of  $R_{OUT}$  can be reduced slightly from the recommended values.

There will be amplitude lost in the series resistor unless the gain is adjusted to compensate; this effect is most noticeable with heavy loads ( $R_L < 150\Omega$ ).

An alternative approach is to place  $R_{OUT}$  inside the feedback loop as shown in Figure 42. This will preserve gain accuracy, but will still limit maximum output voltage swing.

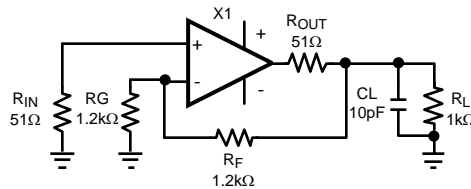


Figure 42. Series Output Resistor Inside Feedback Loop

## INVERTING INPUT PARASITIC CAPACITANCE

Parasitic capacitance is any capacitance in a circuit that was not intentionally added. It is produced through electrical interaction between conductors and can be reduced but never entirely eliminated. Most parasitic capacitances that cause problems are related to board layout or lack of termination on transmission lines. Please see [LAYOUT CONSIDERATIONS](#) for hints on reducing problems due to parasitic capacitances on board traces. Transmission lines should be terminated in their characteristic impedance at both ends.

High speed amplifiers are sensitive to capacitance between the inverting input and ground or power supplies. This shows up as gain peaking at high frequency. The capacitor raises device gain at high frequencies by making  $R_G$  appear smaller. Capacitive output loading will exaggerate this effect.

One possible remedy for this effect is to slightly increase the value of the feedback (and gain set) resistor. This will tend to offset the high frequency gain peaking while leaving other parameters relatively unchanged. If the device has a capacitive load as well as inverting input capacitance, using a series output resistor as described in [DRIVING CAPACITIVE LOADS](#) will help.

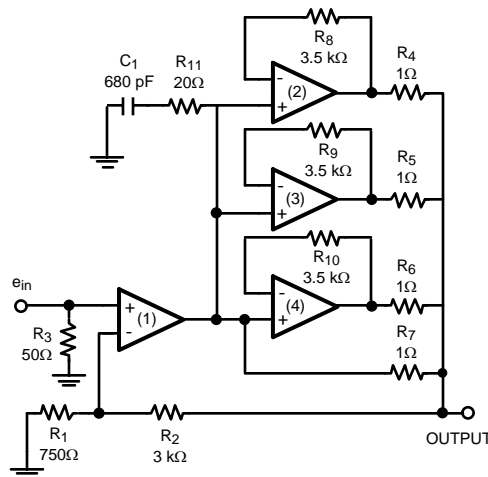


Figure 43. High Output Current Composite Amplifier

When higher currents are required than a single amplifier can provide, the circuit of [Figure 43](#) can be used. Although the example circuit was intended for the LMH6725 quad op amp, higher thermal efficiency can be obtained by using four separate SOIC op amps. Careful attention to a few key components will optimize performance from this circuit. The first thing to note is that the buffers need slightly higher value feedback resistors than if the amplifiers were individually configured. As well,  $R_{11}$  and  $C_1$  provide mid circuit frequency compensation to further improve stability. The composite amplifier has approximately twice the phase delay of a single circuit. The larger values of  $R_8$ ,  $R_9$  and  $R_{10}$ , as well as the high frequency attenuation provided by  $C_1$  and  $R_{11}$ , ensure that the circuit does not oscillate.

Resistors  $R_4$ ,  $R_5$ ,  $R_6$ , and  $R_7$  are necessary to ensure even current distribution between the amplifiers. Since they are inside the feedback loop they have no effect on the gain of the circuit. The circuit shown in [Figure 43](#) has a gain of 5. The frequency response of this circuit is shown in [Figure 44](#).

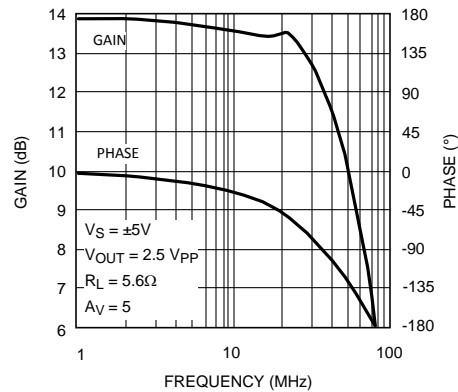


Figure 44. Composite Amplifier Frequency Response

## LAYOUT CONSIDERATIONS

Whenever questions about layout arise, use the evaluation board as a guide. Evaluation boards are shipped with sample requests.

To reduce parasitic capacitances ground and power planes should be removed near the input and output pins. Components in the feedback loop should be placed as close to the device as possible. For long signal paths controlled impedance lines should be used, along with impedance matching at both ends.

Bypass capacitors should be placed as close to the device as possible. Bypass capacitors from each rail to ground are applied in pairs. The larger electrolytic bypass capacitors can be located anywhere on the board; however, the smaller ceramic capacitors should be placed as close to the device as possible.

## VIDEO PERFORMANCE

The LMH6723/LMH6724/LMH6725 has been designed to provide good performance with both PAL and NTSC composite video signals. The LMH6723/LMH6724/LMH6725 is specified for PAL signals. Typically, NTSC performance is marginally better due to the lower frequency content of the signal. Performance degrades as the loading is increased; therefore, best performance will be obtained with back terminated loads. The back termination reduces reflections from the transmission line and effectively masks transmission line and other parasitic capacitances from the amplifier output stage. [Figure 40](#) shows a typical configuration for driving a 75Ω cable. The amplifier is configured for a gain of 2 to make up for the 6dB of loss in  $R_{OUT}$ .

## SINGLE 5V SUPPLY VIDEO

With a 5V supply the LMH6723/LMH6724/LMH6725 is able to handle a composite NTSC video signal, provided that the signal is AC coupled and level shifted so that the signal is centered around  $V_{CC}/2$ .

## POWER DISSIPATION

Follow these steps to determine the maximum power dissipation for the LMH6723/LMH6724/LMH6725:

1. Calculate the quiescent (no-load) power:  $P_{AMP} = I_{CC} * (V_S)$

where  $V_S = V^+ - V^-$

2. Calculate the RMS power dissipated in the output stage:  $P_D \text{ (rms)} = \text{rms} ((V_S - V_{OUT}) * I_{OUT})$  where  $V_{OUT}$  and  $I_{OUT}$  are the voltage and current of the external load and  $V_S$  is the supply voltage.
3. Calculate the total RMS power:  $P_T = P_{AMP} + P_D$

The maximum power that the LMH6723/LMH6724/LMH6725 package can dissipate at a given temperature can be derived with the following equation:

$$P_{MAX} = (150^\circ - T_{AMB}) / \theta_{JA}$$

where

- $T_{AMB}$  = Ambient temperature ( $^\circ\text{C}$ )
- $\theta_{JA}$  = Thermal resistance, from junction to ambient, for a given package ( $^\circ\text{C}/\text{W}$ ) (1)

For the SOIC-8 package  $\theta_{JA}$  is  $166^\circ\text{C}/\text{W}$  and for the SOT-23-5 it is  $230^\circ\text{C}/\text{W}$ . The SOIC-14 has a  $\theta_{JA}$  of  $130^\circ\text{C}/\text{W}$ . The TSSOP-14 has a  $\theta_{JA}$  of  $160^\circ\text{C}/\text{W}$ .

## ESD PROTECTION

The LMH6723/LMH6724/LMH6725 is protected against electrostatic discharge (ESD) on all pins. The LMH6723/LMH6725 will survive 2000V Human Body Model or 200V Machine Model events.

Under closed loop operation the ESD diodes have no effect on circuit performance. There are occasions, however, when the ESD diodes will be evident. If the LMH6723/LMH6724/LMH6725 is driven into a slewing condition the ESD diodes will clamp large differential voltages until the feedback loop restores closed loop operation. Also, if the device is powered down and a large input signal is applied, the ESD diodes will conduct.

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**REVISION HISTORY**

<b>Changes from Revision G (April 2013) to Revision H</b>	<b>Page</b>
• Changed layout of National Data Sheet to TI format .....	<a href="#">18</a>

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**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
LMH6723MA	ACTIVE	SOIC	D	8	95	TBD	Call TI	Call TI	-40 to 85	LMH67 23MA	<a href="#">Samples</a>
LMH6723MA/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMH67 23MA	<a href="#">Samples</a>
LMH6723MAX	ACTIVE	SOIC	D	8	2500	TBD	Call TI	Call TI	-40 to 85	LMH67 23MA	<a href="#">Samples</a>
LMH6723MAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMH67 23MA	<a href="#">Samples</a>
LMH6723MF	ACTIVE	SOT-23	DBV	5	1000	TBD	Call TI	Call TI	-40 to 85	AB1A	<a href="#">Samples</a>
LMH6723MF/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	AB1A	<a href="#">Samples</a>
LMH6723MFX	ACTIVE	SOT-23	DBV	5	3000	TBD	Call TI	Call TI	-40 to 85	AB1A	<a href="#">Samples</a>
LMH6723MFX/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	AB1A	<a href="#">Samples</a>
LMH6724MA	ACTIVE	SOIC	D	8	95	TBD	Call TI	Call TI	-40 to 85	LMH67 24MA	<a href="#">Samples</a>
LMH6724MA/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMH67 24MA	<a href="#">Samples</a>
LMH6724MAX	ACTIVE	SOIC	D	8	2500	TBD	Call TI	Call TI	-40 to 85	LMH67 24MA	<a href="#">Samples</a>
LMH6724MAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMH67 24MA	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

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**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMH6723MAX	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMH6723MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMH6723MF	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMH6723MF/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMH6723MFX	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMH6723MFX/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMH6724MAX	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMH6724MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

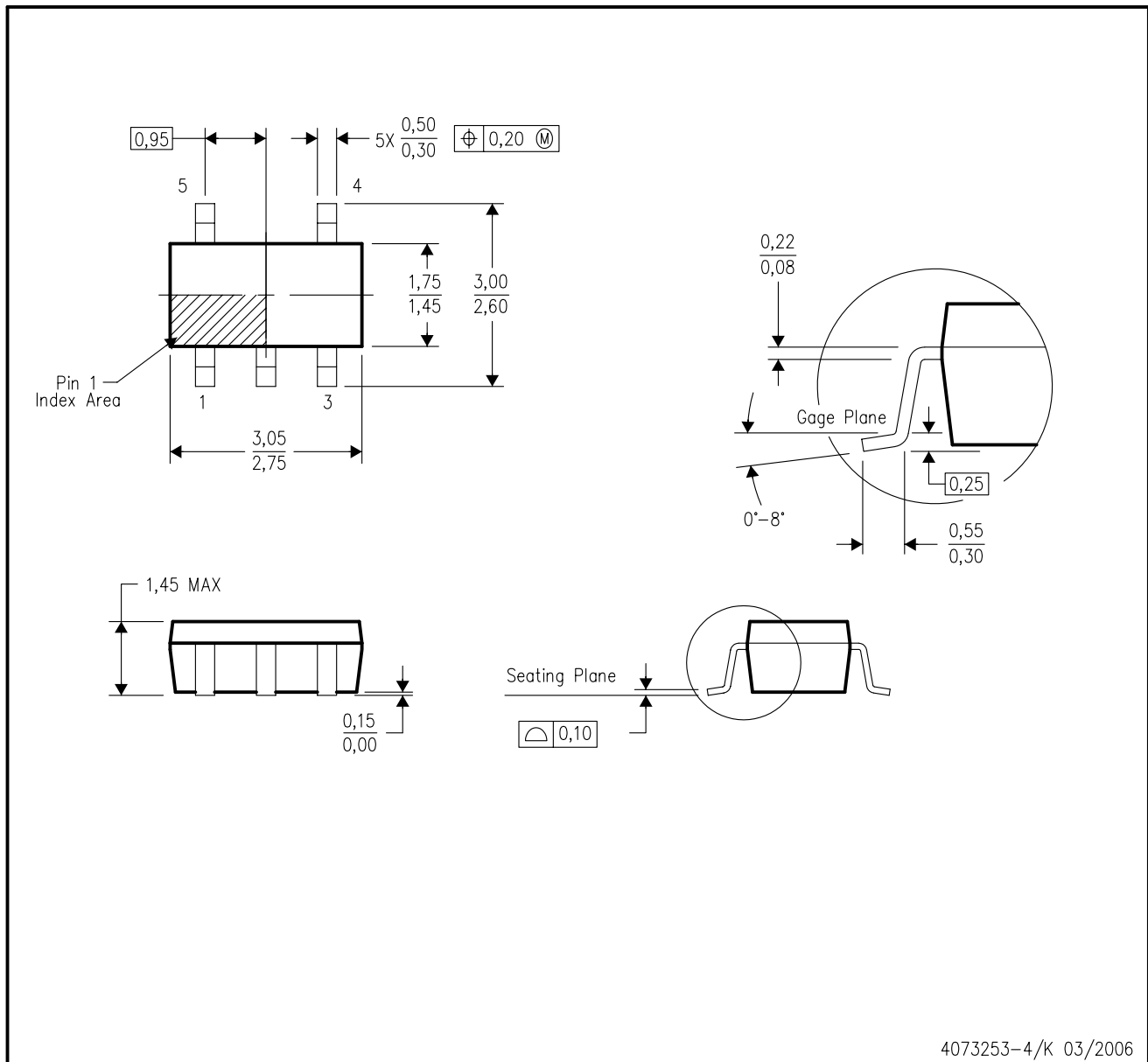
**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMH6723MAX	SOIC	D	8	2500	367.0	367.0	35.0
LMH6723MAX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LMH6723MF	SOT-23	DBV	5	1000	210.0	185.0	35.0
LMH6723MF/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0
LMH6723MFX	SOT-23	DBV	5	3000	210.0	185.0	35.0
LMH6723MFX/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LMH6724MAX	SOIC	D	8	2500	367.0	367.0	35.0
LMH6724MAX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

DBV (R-PDSO-G5)

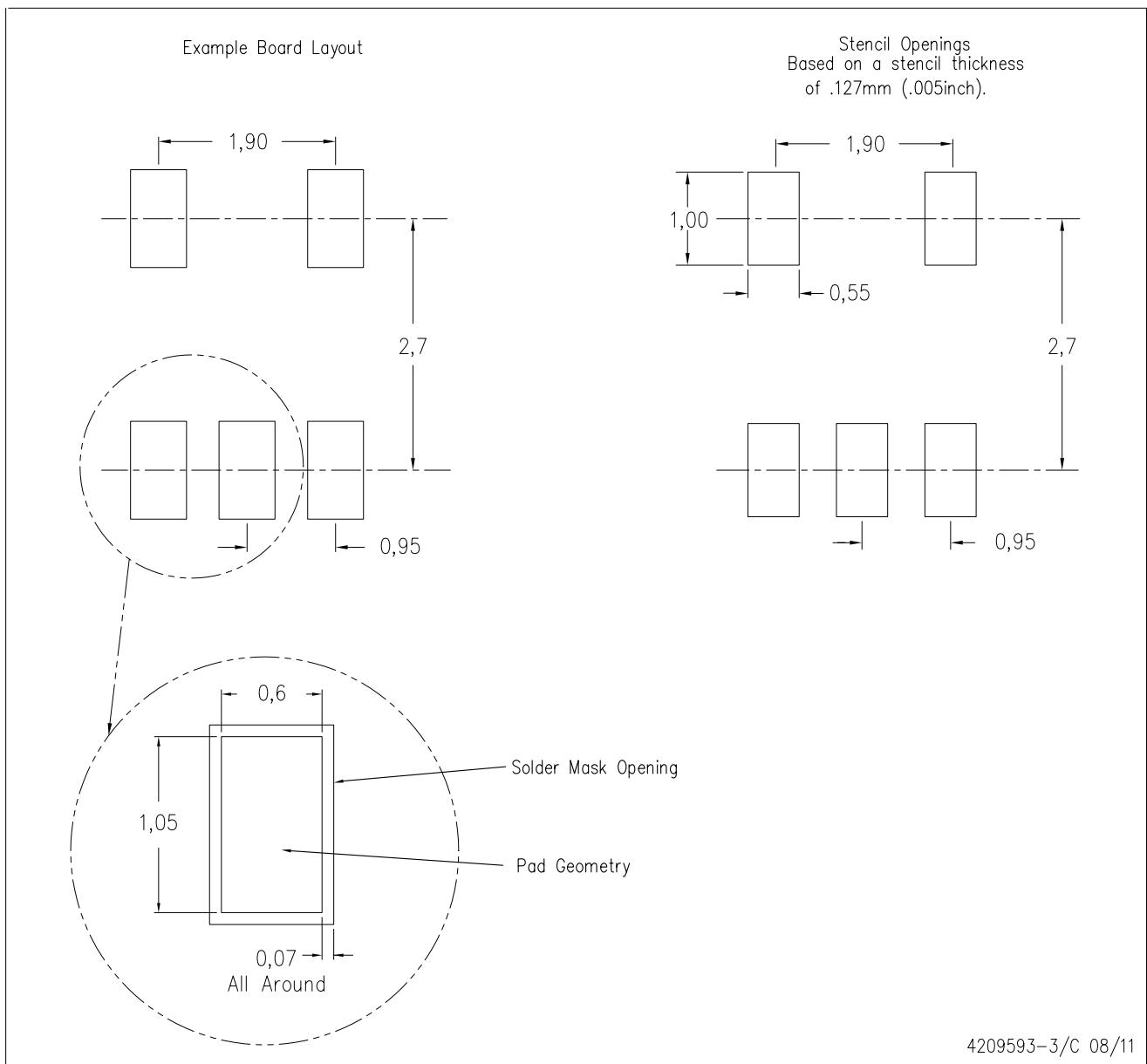
PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-178 Variation AA.

DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
  - D. Publication IPC-7351 is recommended for alternate designs.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).  
 B. This drawing is subject to change without notice.  
 C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.  
 D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.  
 E. Reference JEDEC MS-012 variation AA.

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TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

### Products

Audio	<a href="http://www.ti.com/audio">www.ti.com/audio</a>
Amplifiers	<a href="http://amplifier.ti.com">amplifier.ti.com</a>
Data Converters	<a href="http://dataconverter.ti.com">dataconverter.ti.com</a>
DLP® Products	<a href="http://www.dlp.com">www.dlp.com</a>
DSP	<a href="http://dsp.ti.com">dsp.ti.com</a>
Clocks and Timers	<a href="http://www.ti.com/clocks">www.ti.com/clocks</a>
Interface	<a href="http://interface.ti.com">interface.ti.com</a>
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